

FEATURES

1. Approx. 1/2 the space compared with the mounting of a set of 1 Form A and 1 Form B photoMOS relays
2. Applicable for 1 Form A 1 Form B use as well as two independent 1 Form A and 1 Form B use
3. Low thermal electromotive force (Approx. 1 μ V)
4. Eliminates the need for a counter electromotive force protection diode in the drive circuits on the input side
5. Controls load currents up to 0.13 A with an input current of 5 mA with load voltage of 400 V
6. High speed switching: operate time of 300 μ s typical.
7. Eliminates the need for a power supply to drive the power MOSFET

8. Extremely low closed-circuit offset voltages to enable control of small analog signals without distortion (Typical 100 pA at 400 V)
9. Stable on resistance

TYPICAL APPLICATIONS

- High-speed inspection machines
- Telephone equipment
- Computer

RoHS Directive compatibility information
<http://www.mew.co.jp/ac/e/environment/>

TYPES

Type	Output rating*		Part No.				Packing quantity	
	Load voltage	Load current	Through hole terminal	Surface-mount terminal			Tube	Tape and reel
			Tube packing style	Tape and reel packing style				
				Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side			
AC/DC type	400 V	100 mA	AQW614	AQW614A	AQW614AX	AQW614AZ	1 tube contains 40 pcs. 1 batch contains 400 pcs.	1,000 pcs.

*Indicate the peak AC and DC values.

Note: For space reasons, the SMD terminal shape indicator "A" and the package style indicator "X" or "Z" are not marked on the relay.

RATINGS

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQW614(A)	Remarks
Input	LED forward current	I_F	50 mA	
	LED reverse voltage	V_R	5 V	
	Peak forward current	I_{FP}	1 A	$f = 100$ Hz, Duty factor = 0.1%
	Power dissipation	P_{in}	75 mW	
Output	Load voltage	V_L	400 V	
	Continuous load current	I_L	0.1 A (0.13 A)	Peak AC, DC () : in case of using only 1a or 1b, 1 channel
	Peak load current	I_{peak}	0.3 A	100 ms (1 shot), $V_L = DC$
	Power dissipation	P_{out}	800 mW	
Total power dissipation		P_T	850 mW	
I/O isolation voltage		V_{iso}	1,500 V AC	Between input and output/between contact sets
Temperature limits	Operating	T_{opr}	-40°C to +85°C -40°F to +185°F	Non-condensing at low temperatures
	Storage	T_{stg}	-40°C to +100°C -40°F to +212°F	

GU PhotoMOS (AQW614)

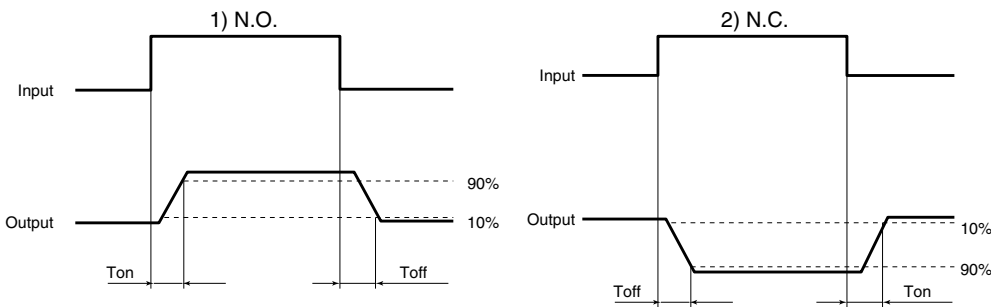
2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	AQW614(A)	Condition	
Input	LED operate (OFF) current	Typical	I_{Fon} (N.O.)	0.9 mA	
		Maximum	I_{Foff} (N.C.)	3 mA	
	LED reverse (ON) current	Minimum	I_{Foff} (N.O.)	0.4 mA	
		Typical	I_{Fon} (N.C.)	0.8 mA	
LED dropout voltage	Typical	V_F	1.25 V (1.14 V at $I_F = 5$ mA)		
	Maximum		1.5 V		
Output	On resistance	Typical	R_{on}	27 Ω	
		Maximum		50 Ω	
	Off state leakage current	Maximum	I_{Leak}	1 μ A	$I_F = 0$ mA (N.O.) $I_F = 5$ mA (N.C.) $V_L = 400$ V
Transfer characteristics	Operate (OFF) time*	Typical	T_{on} (N.O.)	0.28 ms (N.O.) 0.43 ms (N.C.)	
		Maximum		T_{off} (N.C.)	1 ms
	Reverse (ON) time*	Typical	T_{off} (N.O.)	0.04 ms (N.O.) 0.3 ms (N.C.)	
		Maximum		T_{on} (N.C.)	1 ms
	I/O capacitance	Typical	C_{iso}	0.8 pF	
Maximum		1.5 pF			
Initial I/O isolation resistance	Minimum	R_{iso}	1,000 M Ω	500 V DC	

Note: Recommendable LED forward current $I_F = 5$ mA.

For type of connection.

*Operate/Reverse time

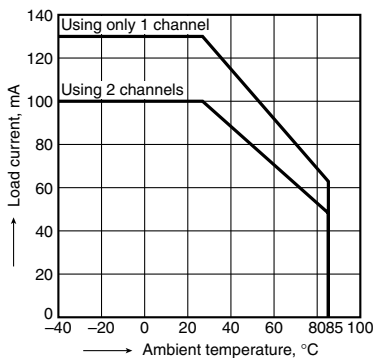


- For Dimensions.
- For Schematic and Wiring Diagrams.
- For Cautions for Use.

REFERENCE DATA

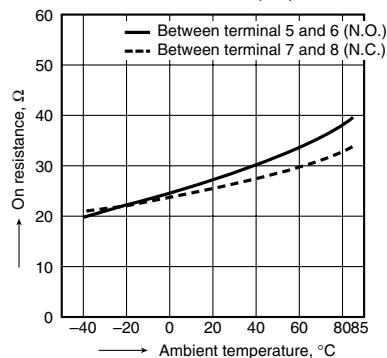
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
LED current: 5 mA; Load voltage: 400 V (DC);
Continuous load current: 100 mA (DC)



3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA;
Load voltage: 400 V (DC);
Continuous load current: 100 mA (DC)

